

TOSHIBA CMOS Linear Integrated Circuit Silicon Monolithic

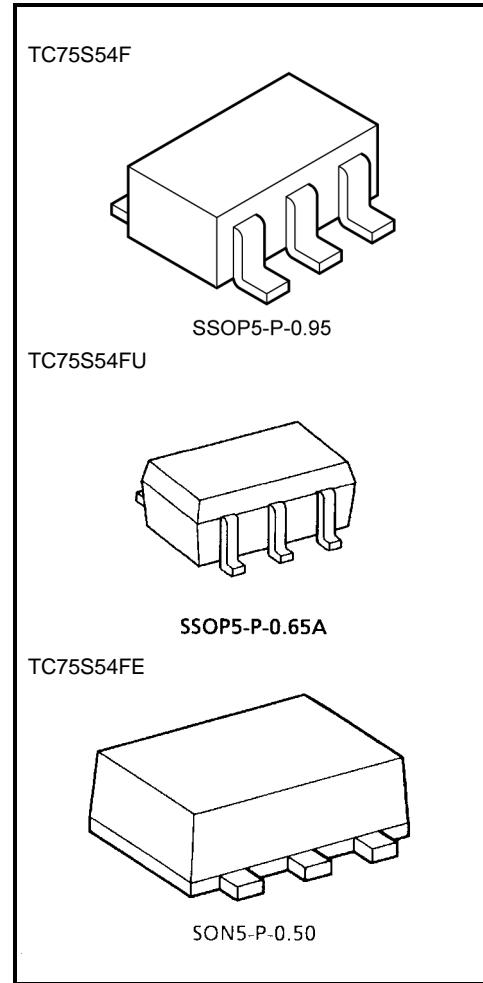
TC75S54F, TC75S54FU, TC75S54FE

Single Operational Amplifier

The TC75S54F/TC75S54FU/TC75S54FE is a CMOS single-operation amplifier which incorporates a phase compensation circuit. It is designed for use with a low-voltage, low-current power supply; this differentiates this device from conventional general-purpose bipolar op-amps.

Features

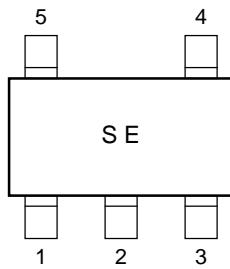
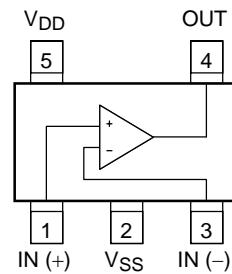
- Low-voltage operation : $V_{DD} = \pm 0.9 \sim 3.5$ V or $1.8 \sim 7$ V
- Low-current power supply : $IDD (V_{DD} = 3$ V) = $100 \mu A$ (typ.)
- Built-in phase-compensated op-amp, obviating the need for any external device
- Ultra-compact package



Weight
 SSOP5-P-0.95 : 0.014 g (typ.)
 SSOP5-P-0.65A : 0.006 g (typ.)
 SON5-P-0.50 : 0.003 g (typ.)

Maximum Ratings ($T_a = 25^\circ C$)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{DD}, V_{SS}	7	V
Differential input voltage	DV_{IN}	± 7	V
Input voltage	V_{IN}	$V_{DD} \sim V_{SS}$	V
Power dissipation	TC75S54F/FU	200	mW
	TC75S54FE	100	
Operating temperature	T_{opr}	-40~85	°C
Storage temperature	T_{stg}	-55~125	°C

Marking (top view)**Pin Connection (top view)****Electrical Characteristics****DC Characteristics ($V_{DD} = 3.0 \text{ V}$, $V_{SS} = \text{GND}$, $T_a = 25^\circ\text{C}$)**

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Input offset voltage	V_{IO}	1	$R_S = 1 \text{ k}\Omega$	—	2	10	mV
Input offset current	I_{IO}	—	—	—	1	—	pA
Input bias current	I_I	—	—	—	1	—	pA
Common mode input voltage	CMV_{IN}	2	—	0.0	—	2.1	V
Voltage gain(open loop)	G_V	—	—	60	70	—	dB
Maximum output voltage	V_{OH}	3	$R_L \geq 100 \text{ k}\Omega$	2.9	—	—	V
	V_{OL}	4	$R_L \geq 100 \text{ k}\Omega$	—	—	0.1	
Common mode input signal rejection ratio	CMRR	2	$V_{IN} = 0.0\sim2.1 \text{ V}$	60	70	—	dB
Supply voltage rejection ratio	SVRR	1	$V_{DD} = 1.8\sim7.0 \text{ V}$	60	70	—	dB
Supply current	I_{DD}	5	—	—	100	200	μA
Source current	I_{source}	6	—	100	200	—	μA
Sink current	I_{sink}	7	—	200	700	—	μA

DC Characteristics ($V_{DD} = 1.8 \text{ V}$, $V_{SS} = \text{GND}$, $T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Input offset voltage	V_{IO}	1	$R_S = 10 \text{ k}\Omega$	—	2	10	mV
Input offset current	I_{IO}	—	—	—	1	—	pA
Input bias current	I_I	—	—	—	1	—	pA
Common mode input voltage	CMV_{IN}	2	—	0.2	—	0.9	V
Voltage gain (open loop)	G_V	—	—	60	70	—	dB
Maximum output voltage	V_{OH}	3	$R_L \geq 100 \text{ k}\Omega$	1.7	—	—	V
	V_{OL}	4	$R_L \geq 100 \text{ k}\Omega$	—	—	0.1	
Supply current	I_{DD}	5	—	—	80	160	μA
Source current	I_{source}	6	—	80	160	—	μA
Sink current	I_{sink}	7	—	200	600	—	μA

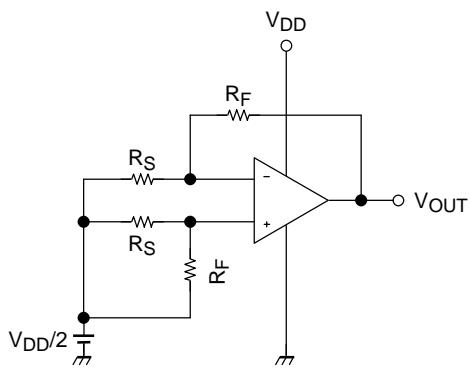
AC Characteristics ($V_{DD} = 3.0$ V, $V_{SS} = GND$, $T_a = 25^\circ C$)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Slew rate	SR	—	—	—	0.7	—	V/ μ s
Unity gain cross frequency	f _T	—	—	—	0.9	—	MHz

AC Characteristics ($V_{DD} = 1.8$ V, $V_{SS} = GND$, $T_a = 25^\circ C$)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Slew rate	SR	—	—	—	0.6	—	V/ μ s
Unity gain cross frequency	f _T	—	—	—	0.8	—	MHz

Test Circuit

1. SVRR, V_{IO} 

• SVRR

For each of the two V_{DD} values, measure the V_{OUT} value, as indicated below, and calculate the value of SVRR using the equation shown.

When $V_{DD} = 1.8$ V, $V_{DD} = V_{DD1}$ and $V_{OUT} = V_{OUT1}$

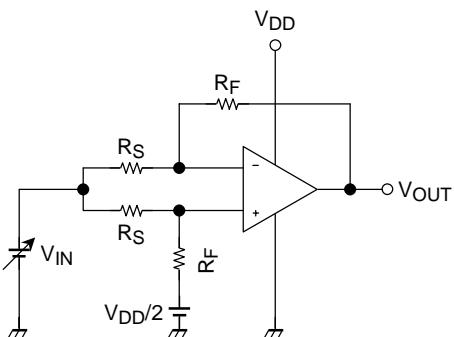
When $V_{DD} = 7.0$ V, $V_{DD} = V_{DD2}$ and $V_{OUT} = V_{OUT2}$

$$SVRR = 20 \log \left(\left| \frac{V_{OUT1} - V_{OUT2}}{V_{DD1} - V_{DD2}} \right| \times \frac{R_S}{R_F + R_S} \right)$$

• V_{IO}

Measure the value of V_{OUT} and calculate the value of V_{IO} using the following equation.

$$V_{IO} = \left(V_{OUT} - \frac{V_{DD}}{2} \right) \times \frac{R_S}{R_F + R_S}$$

2. CMRR, CMV_{IN} 

• CMRR

Measure the V_{OUT} value, as indicated below, and calculate the value of the CMRR using the equation shown.

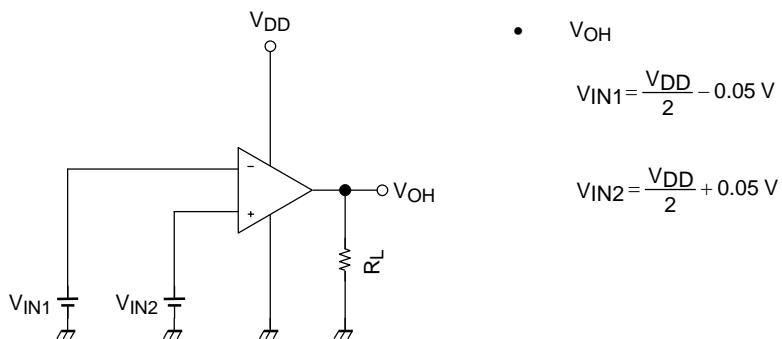
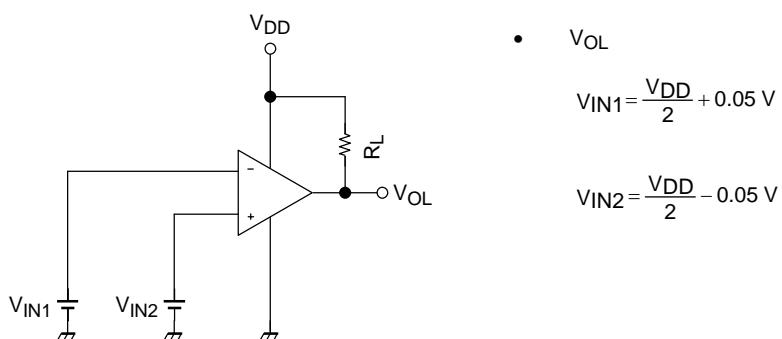
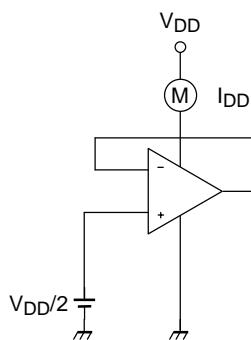
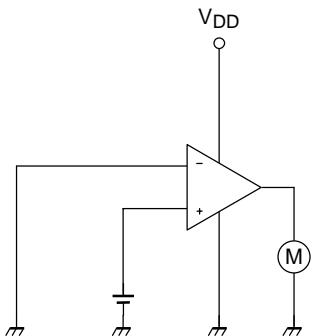
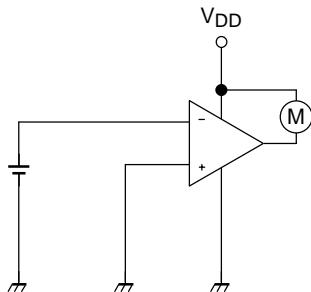
When $V_{IN} = 0.0$ V, $V_{IN} = V_{IN1}$ and $V_{OUT} = V_{OUT1}$

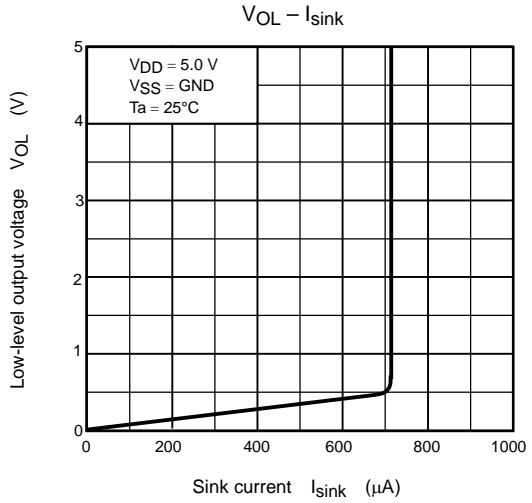
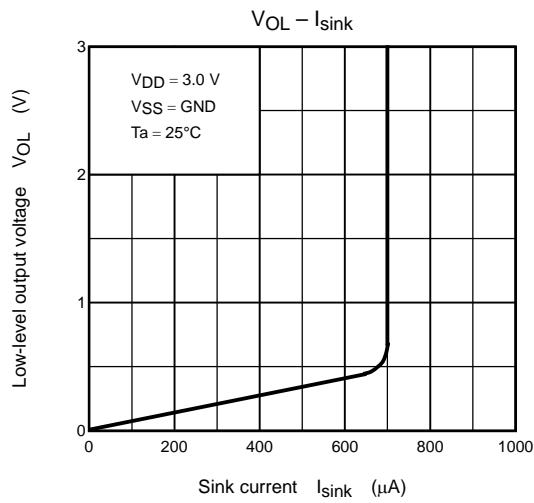
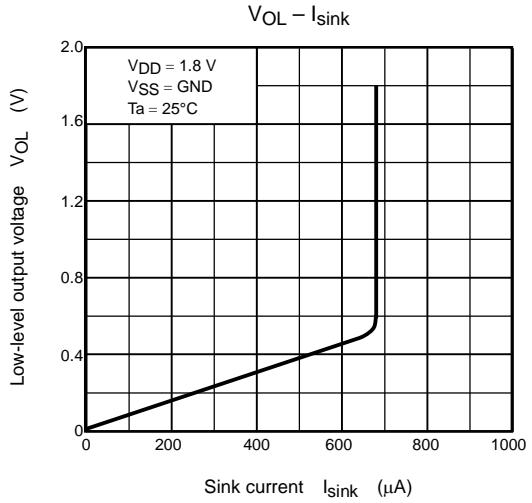
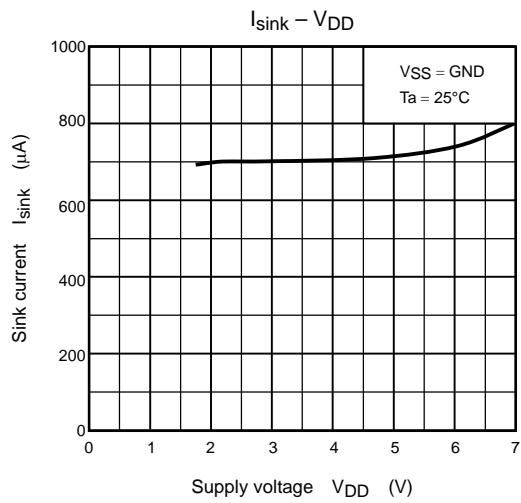
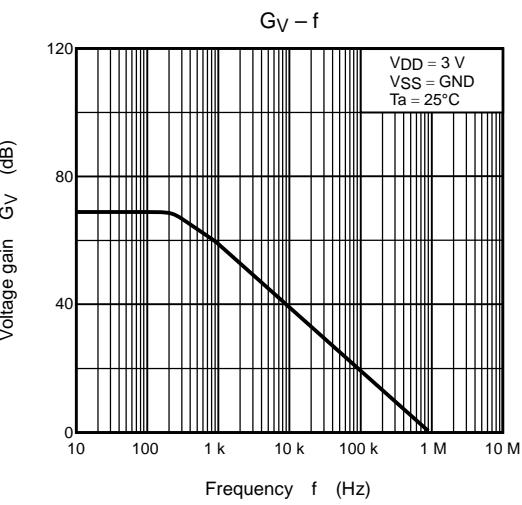
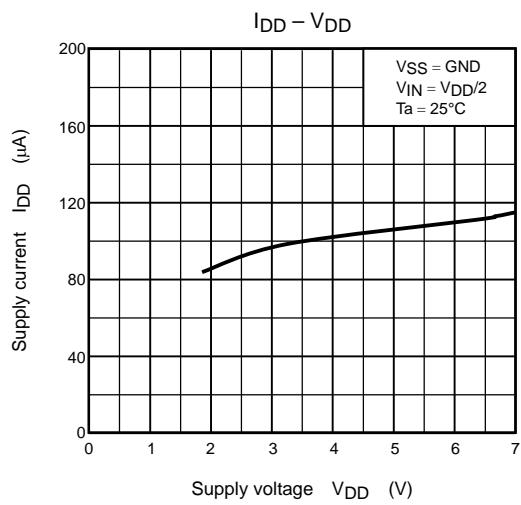
When $V_{IN} = 2.1$ V, $V_{IN} = V_{IN2}$ and $V_{OUT} = V_{OUT2}$

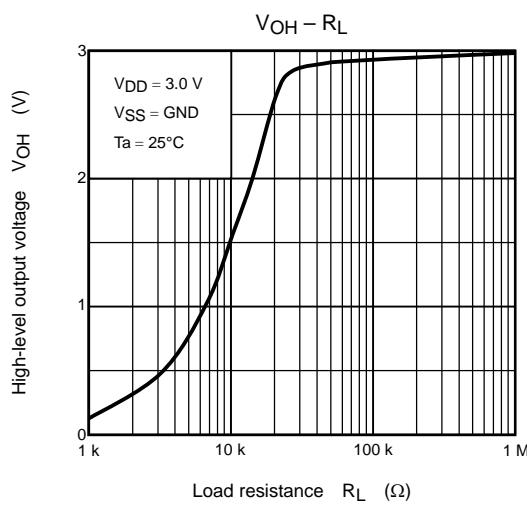
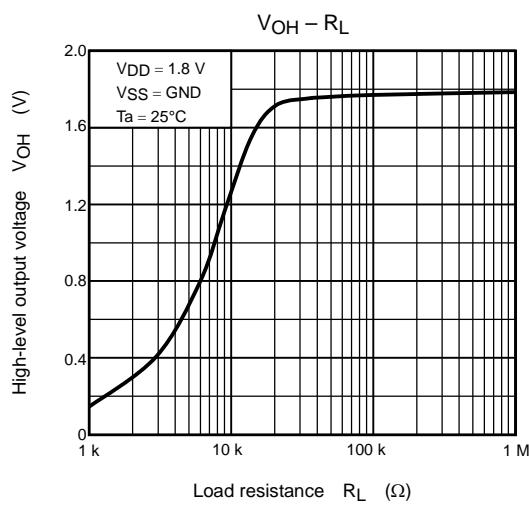
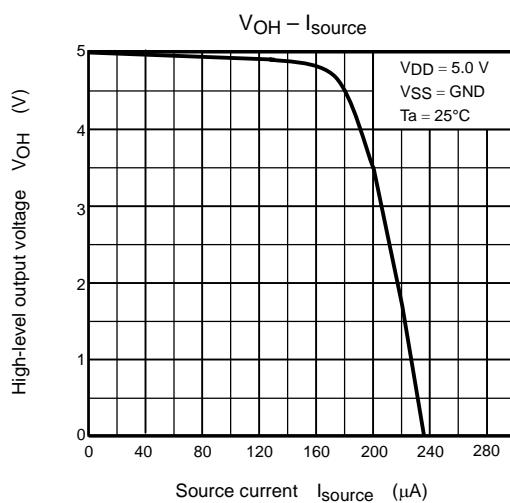
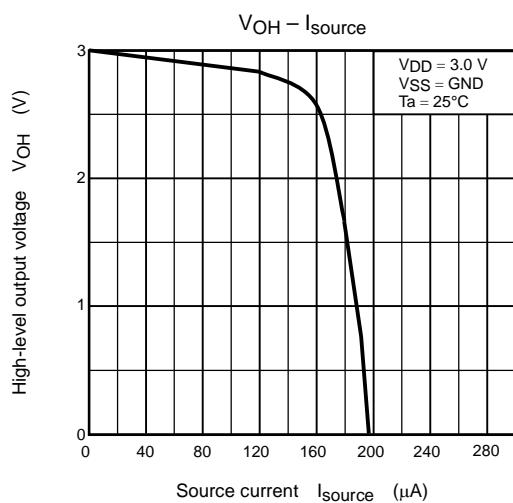
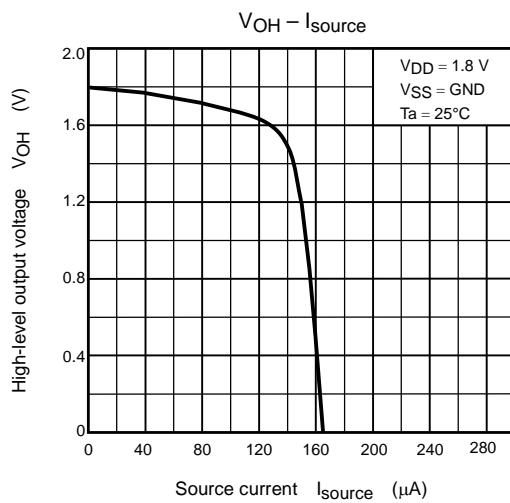
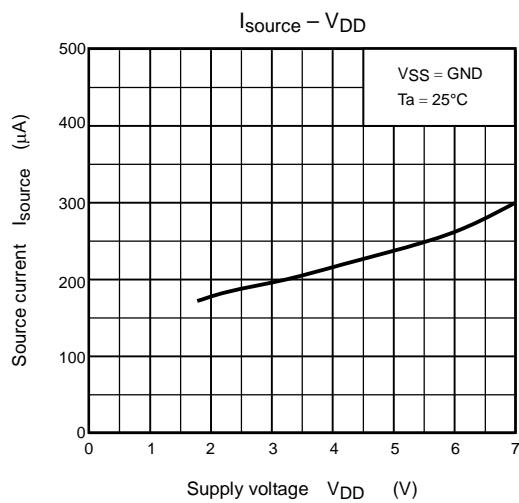
$$CMRR = 20 \log \left(\left| \frac{V_{OUT1} - V_{OUT2}}{V_{IN1} - V_{IN2}} \right| \times \frac{R_S}{R_F + R_S} \right)$$

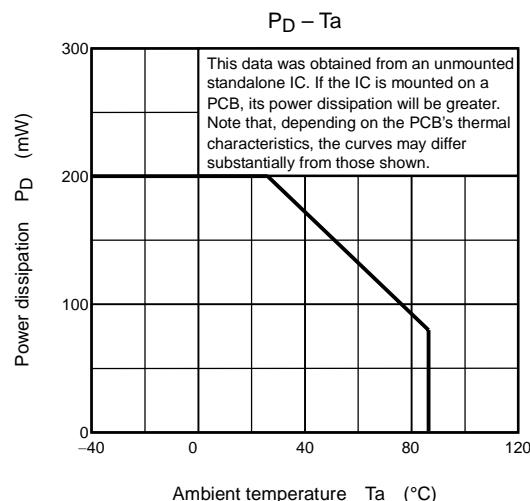
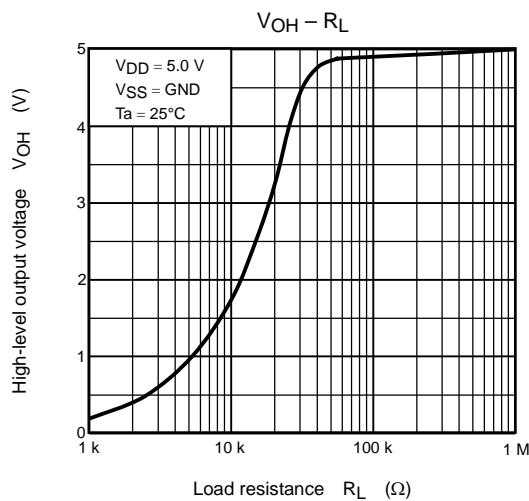
• CMV_{IN}

Input range within which the CMRR specification guarantees V_{OUT} value (as varied by the V_{IN} value).

3. V_{OH} 4. V_{OL} 5. I_{DD} 6. I_{source} 7. I_{sink} 



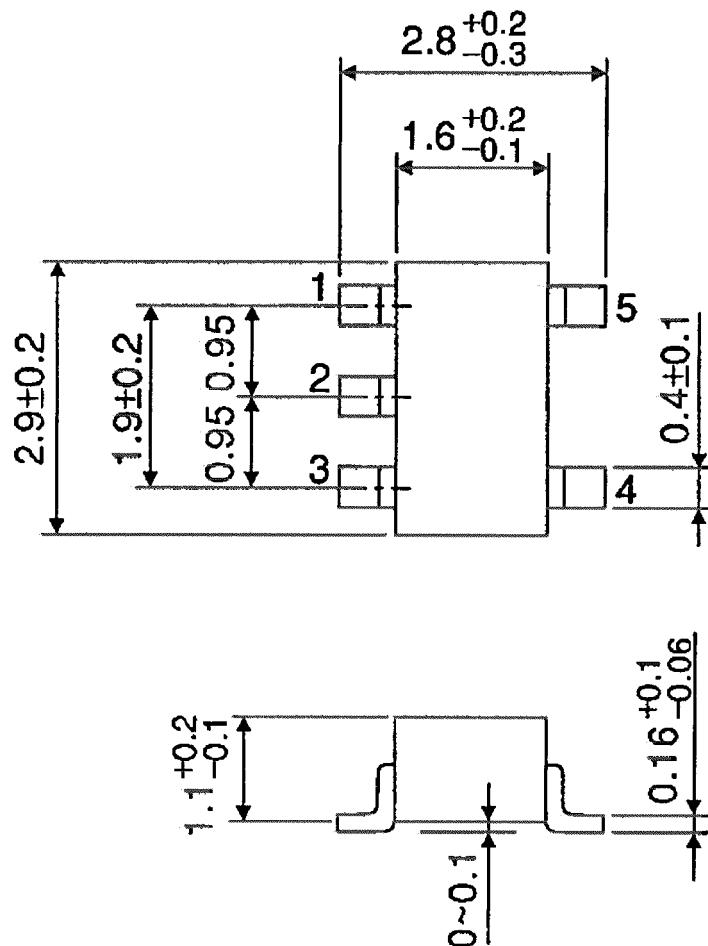




Package Dimensions

SSOP5-P-0.95

Unit : mm

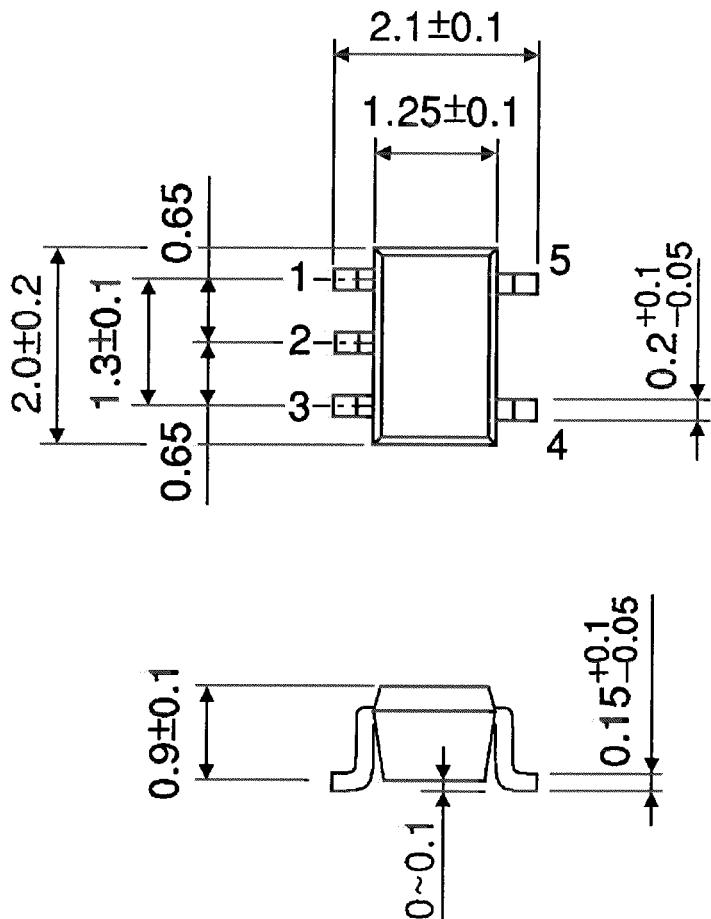


Weight: 0.014 g (typ.)

Package Dimensions

SSOP5-P-0.65A

Unit : mm

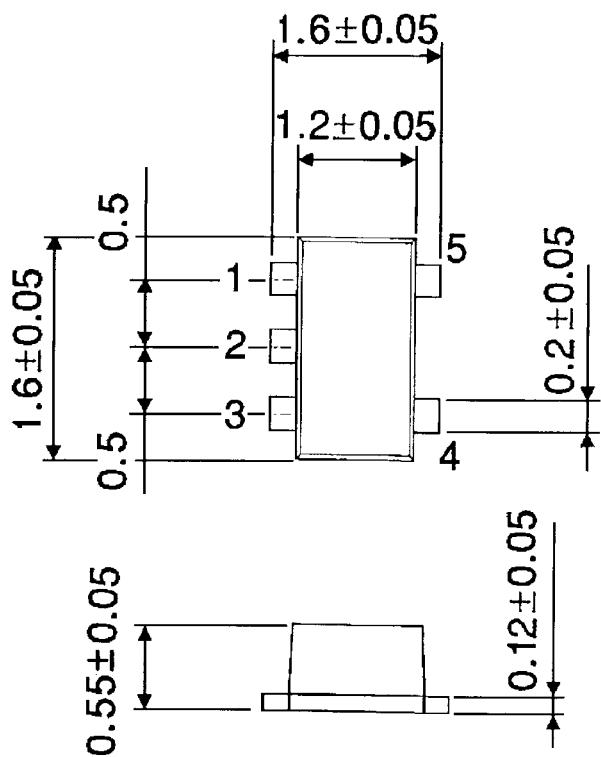


Weight: 0.006 g (typ.)

Package Dimensions

SON5-P-0.50

Unit : mm



Weight: 0.003 g (typ.)

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